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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Jennifer Stone-Sundberg, et al.

Title: SPINEL BOULES, WAFERS, AND METHODS FOR FABRICATING  
SAME

Application No.: 10/668,610 Filed: September 23, 2003

Examiner: Stephen J. Stein Group Art Unit: 1775

Atty. Docket No.: 1035-BI4281

COMMISSIONER FOR PATENTS  
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Alexandria, VA 22313-1450

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Form(s) PTO/SB/08A and/or PTO/SB/08B or PTO/1449  
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to the Examiner's attention in the above-identified application. Citation of such information shall not be construed as:

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*E.K. Dougherty*  
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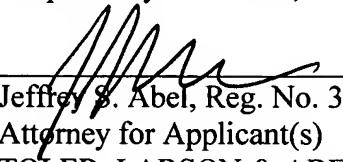
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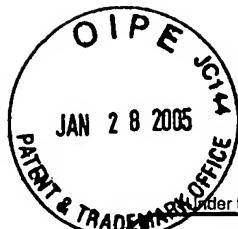
Should any PTO fees be necessary for entry of this Information Disclosure Statement, the undersigned hereby authorizes the Commissioner to charge Deposit Account 50-2469.

Date

1/25/05

Respectfully submitted,

  
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JAN 28 2005

PTO/SB/08A (08-03)

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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Sheet 1

of 3

**Complete if Known**

Application Number	10/668,610
Filing Date	September 23, 2003
First Named Inventor	Jennifer Stone-Sundberg
Art Unit	1775
Examiner Name	Stephen J. Stein

Attorney Docket Number 1035-BI4281

**U. S. PATENT DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Document Number Number-Kind Code <sup>2</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
AA	US-	4,963,520	10/16/1990	Yoo, et al.	
AB	US-	5,982,796	11/09/1999	Kokta, et al.	
AC	US-	5,654,973	08/05/1997	Stultz, et al.	
AD	US-	5,557,624	09/17/1996	Stultz, et al.	
AE	US-	6,366,596	04/02/2002	Yin, et al.	
AF	US-	6,023,479	02/08/2000	Thony, et al.	
AG	US-				
AH	US-				
AI	US-				
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**FOREIGN PATENT DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document Country Code <sup>3</sup> -Number <sup>4</sup> -Kind Code <sup>5</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages Or Relevant Figures Appear	T <sup>6</sup>
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				<b>Filing Date</b>	September 23, 2003
				<b>First Named Inventor</b>	Jennifer Stone-Sundberg
				<b>Art Unit</b>	1775
				<b>Examiner Name</b>	Stephen J. Stein
Sheet	2	of	3	Attorney Docket Number	1035-BI4281

<b>NON PATENT LITERATURE DOCUMENTS</b>				
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.		
	BA	Efimov, A.N., et al., "Onan Unusual Azimuthal Orientation Relationship in the System Gallium Nitride Layer on Spinel Substrate", CRYSTALLOGRAPHY REPORTS, 45(2): 312-317 (2000).		T <sup>2</sup>
	BB	Sun C.J., et al., "Mg-doped green light emitting diodes over cubic (1 1 1) MgAl2O4 substrate", APP. PHYS. LETT. 72(19): 2361-2363 (1998).		
	BC	Efimov, A.N., et al., "Symmetry constraints and epitaxial growth on non-isomorphic substrate", THIN SOLID FILMS 260: 111-117 (1995).		
	BD	George, T., et al., "Novel symmetry in the growth of gallium nitride on magnesium aluminate substrates", APPL. PHYS. LETT. 68(3): 337-339 (1996).		
	BE	Sun C.J., et al., "Deposition of high quality wurtzite GaN films over cubic (1 1 1) MgAl2O4 substrates using low pressure and metalorganic chemical vapor deposition, " APPL. PHYS. LETT. 68(8): 1129-1131 (1996).		
	BF	Nakamura, S., et al., "Characteristics of InGaN multi-quantum-well-structure laser diodes, " APPL. PHYS. LETT. 68(23): 3269-3271 (1996).		
	BG	Khan, M.A., et al., "Cleaved cavity optically pumped InGaN-GaN laser grown on spinel substrates," APPL. PHYS. LETT. 69(16): 2418-2420 (1996).		
	BH	Tempel, A., et al., "Nachweis von Stapelfehlern in GaN-Exitaxieschichten mittels Elektronenbeugung," KRISTALL UND TECHNIK 10(7): 741-746 (1975).		
	BI	Tempel, A., et al., "Zur Epitaxie von Galliumnitrid auf nichtstoechiometrischem Spinell im System GaC1/NH3/He, " KRISTALL UND TECHNIK 10(7): 747-758 (1975)		
	BJ	K.V. Yumashev, "Saturable absorber Co2+: MgAl2O3 crystal for Q switching of 1.34- $\mu$ m Nd3+: YAlO3 and 1.54- $\mu$ m Er3+: glass lasers," APPLIED OPTICS 38(30): 6343-6346 (1999).		

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	CA	Camargo, M.B., et al., "Co2+ Y3Sc2Ga3O12 (YSGG) Passive Q-Switch for Infared Erbium Lasers," submitted to LEOS in 1994.	
	CB	Mikhailov, V.P., et al., "Passive Q-switch performance at 1.3u (1.5u) and nonlinear spectroscopy of Co2+: MgAl2O4 and Co2+: LaMgAl11O9 cyrstals," OSA TOPS VOL. 26 Advanced Solid-State Lasers, pp. 317-324 (1999).	
	CC	Stulz, R.D., et al., "Diavalent Uranium and Cobalt Saturable Absorber Q-Switches at 1.5um," OSA Proceedings on Advanced Solid-State Lasers, 24:460-464 (1995).	
	CD	Birnbaum, M., et al., " Co2+: ZnSe Saturable Absorber Q-Switch for the 1.54 Um Er3+: Yb3+: Glass Laser," OSA TOPS Vol. 10 Advanced Solid State Lasers, pp. 148-151 (1997).	
	CE	Machida, H., et al., "difficulties encountered during the Czochralksi growth of TiO2 single crystals," JOURNAL OF CYRSTAL GROWTH, 112: 835-837 (1997).	
	CF	Camargo, M.B., et al., "Broad-band 1.54 um Saturable Absorber Q-switch with Co2+," submitted to ASSL in 1995.	
	CG	Yumashev, K.V., et al., "Nonlinear spectroscopy and passive Q-switching operation of a Co2+: LaMgAl11O19 crystal," J. OPT. SOC. AM. B, 16(12): 2189-2194 (1999).	
	CH		
	CI		
	CJ		

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